	1
40.00	-

L Number	Hits	Search Text	DB	Time stamp
106	0	singapore-yong-meng-lee.in.	USPAT;	2004/02/09 05:53
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	-
			IBM_TDB	
107	0	singapore.in.	USPAT;	2004/02/09 05:53
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
108	0	pu-dong.in.	USPAT;	2004/02/09 05:53
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	1594		USPAT;	2004/02/07 15:51
		(438/337)).CCLS.	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	_	//HC4E4C5CH\ (HC422000H\ (HC2C54C5H\	IBM_TDB	2004/02/07 15:55
-	4	(("6451656") or ("6413802") or ("6365465")	USPAT	2004/02/07 15:55
	10517	or ("6396108")).PN.	USPAT;	2004/02/07 15:56
-	19517	soi or ((silicon adj on)near2 insulator)	US-PGPUB;	2004/02/07 15:30
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
	1	(((438/151) or (438/164) or (438/311) or	USPAT;	2004/02/07 15:57
_	_	(438/337)).CCLS.) and ((soi or ((silicon adj	US-PGPUB;	2001,02,01 20101
		on)near2 insulator)) and ((double near2	EPO; JPO;	
		gated) near transistor))	DERWENT;	
		J	IBM TDB	
_	28	(soi or ((silicon adj on)near2 insulator))	USPAT;	2004/02/07 15:58
		and ((double near2 gated) near transistor)	US-PGPUB;	
		_	EPO; JPO;	
			DERWENT;	
		·	IBM_TDB	
-	41	(double near2 gated) near transistor	USPAT;	2004/02/09 05:52
			US-PGPUB;	
			EPO; JPO;	
]			DERWENT;	
			IBM_TDB	
-	0		USPAT;	2004/02/07 16:04
		and ((double near2 gated) near transistor))	US-PGPUB;	
		not ((double near2 gated) near transistor)	EPO; JPO;	
			DERWENT;	
		(// 13	IBM_TDB	2004/02/05 35 55
-	13	((double near2 gated) near transistor) not	USPAT;	2004/02/07 16:04
		((soi or ((silicon adj on)near2 insulator))	US-PGPUB;	
		and ((double near2 gated) near transistor))	EPO; JPO;	
			DERWENT;	
	l .		IBM_TDB	l